

# Microstrip Line Test and Results

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## 1 Relevant documents

[Doc1] S.M., “*Microstrip Line Characterization*”, August 2023

## 2 Introduction



Figure 1: Smaller 40 mm line test fixture. Front: 5 mm x 40 mm adhesive copper trace on glass fiber slab. Back: thru-hole SMA connector with m2.5 screws and bolts.

This report contains the results for the microstrip line test produced using vector measurements of the reflection and transmission frequency response of three test fixtures of different lengths. The shorter fixture is shown in Fig. 1. The three fixtures feature a microstrip line built using an adhesive copper strip 5 mm wide on a piece of dielectric composite (Material Under Test) glued on a supporting aluminium slab. Two thru-hole connectors are bolted to the structure with the central pin trimmed to length and soldered to the copper line. From here on, the fixtures are referred to by their line length; respectively: long = 219 mm (L), medium = 146 mm (M), and short = 40mm (S).

The complex propagation coefficient  $\gamma$  extraction procedure is defined in

[Doc1] and applied here with minor modifications. An overview of the methodology and the results of this de-embedding procedure are reported in Section 4.

The error sensitivity to small differences in the average permittivity of the fixtures is derived in Section 5 in an effort to explain the discrepancies found in the results of Section 4.

The procedure for fitting the measured datum to a CST microstrip model is reported in Section 6 along with the resulting permittivity and loss tangent of the *Material Under Test* (MUT).

The conclusions are drawn in Section 7.

### 3 Fixtures assembly and geometrical variability

### 4 De-embedding results

The de-embedding results (virtual transmission line properties) are here presented in terms of:

- Transmissivity, i.e., the S21 of the de embedded length of transmission line, denoted with  $t$ .
- Reflectivity, i.e., the S21 of the de embedded length of transmission line, denoted with  $s$ .
- Effective permittivity  $\varepsilon_{eff}$ .
- Effective loss tangent  $\tan \delta_{eff}$ .

The effective permittivity and loss tangent are for visualization purposes only and are formulated from the low-loss approximation [1] for transmission lines (assuming all loss lumped into the dielectric material and the phase velocity independent of loss).

The effective permittivity is given by

$$\varepsilon_{eff} = \left( \frac{c[\text{unwrap}(\angle t) + n2\pi]}{2\pi f L} \right)^2, \quad (1)$$

where  $c$  is the speed of light,  $L$  is the line length,  $f$  is the frequency and  $n$  an integer to correctly reconstruct the true-time phase delay (usually  $n=0$  if the first sample of  $f$  is small enough).

The loss tangent is defined as

$$\tan \delta_{eff} = -\frac{\ln(|t|)c}{L\pi f \sqrt{\varepsilon_{eff}}}. \quad (2)$$

A better figure that can be used to make the measurement results independent from the physical length  $L$ , is the complex propagation constant

$$\gamma = \alpha + j\beta = \ln(t)/L, \quad (3)$$

used in Section 6 to match the CST model to the measured data.

Note how all the above depend (measurand) exclusively on the transmissivity  $t$ . While, the reflectivity  $s$ , using the de-embedding procedure of [Doc1], can be considered as a function of the de-embedding error, as it should be 0 in the ideal case.

For the measured data, it was noted that the response  $s$  varies changing the gate width from the, originally considered, distance between two reflections to a smaller value. Since this changes improves or degrades the value of  $s$  in different parts of the spectrum, it was chosen to modify the de-embedding algorithm of [Doc1], to sweep over several values for the gate width and then perform a weighted average of the different resulting  $t$ -curves using the  $s$ -curves as a logarithmic weighting factors for every frequency bin .

This sensibility to changes in the gates widths is probably due to some irregularities in the measured transmission lines, far from being perfectly homogeneous due to the manufacturing process. This change in gate length, in theory, should not impact negatively on the overall result as it is equivalent to performing a low-pass filtering of the time impulse response of the transitions to be removed. In fact, the average  $s$  value over frequency reduces when this weighted average technique is introduced.

Moreover, instead of always using the longer transmission line to generate the transition scattering matrices to de-embed the shorter transmission line, all combinations of measurement/simulation pairs are computed. Although using the longer line as reference provides the best theoretical frequency resolution, is interesting to see what happens in the reversed case where the transition scattering parameters have a naturally shorter (low-pass) time response, and hence a smoother shape in frequency.

The resulting de-embedded virtual lines can therefore either have a causal or an anti-causal response. For ease of comparison all the signs in the data plots are normalized to always represent the equivalent anti-causal transmission lines, e.g., “LS” is the *anti-causal* (negative length) line obtained de-embedding the line S from the transitions T-matrices obtained from the response of L, and vice versa “SL” is the *causal* line of identical positive length.

#### 4.1 Simulated data reference

In order to validate the modified de-embedding algorithm ...

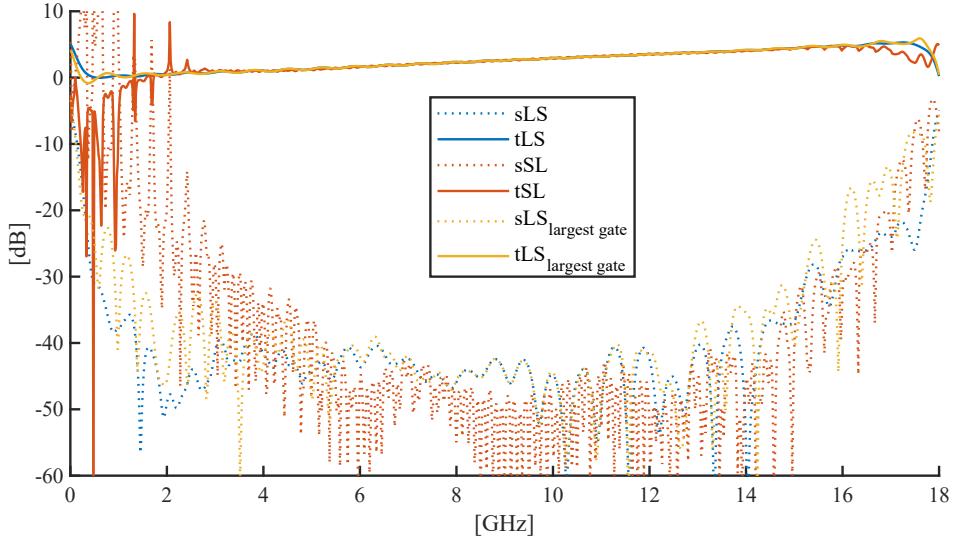


Figure 2: De-embedding results from full wave simulations of a 40 mm (S) and a 219 mm (L) test fixtures. Solid lines: transmissivity (s), dotted lines: reflectivity (t); for all the combinations plus LS deembeding without gate width variation. The transmissivity sign is chosen to always correspond to a negative-length section of lossy transmission line (for ease of comparison).

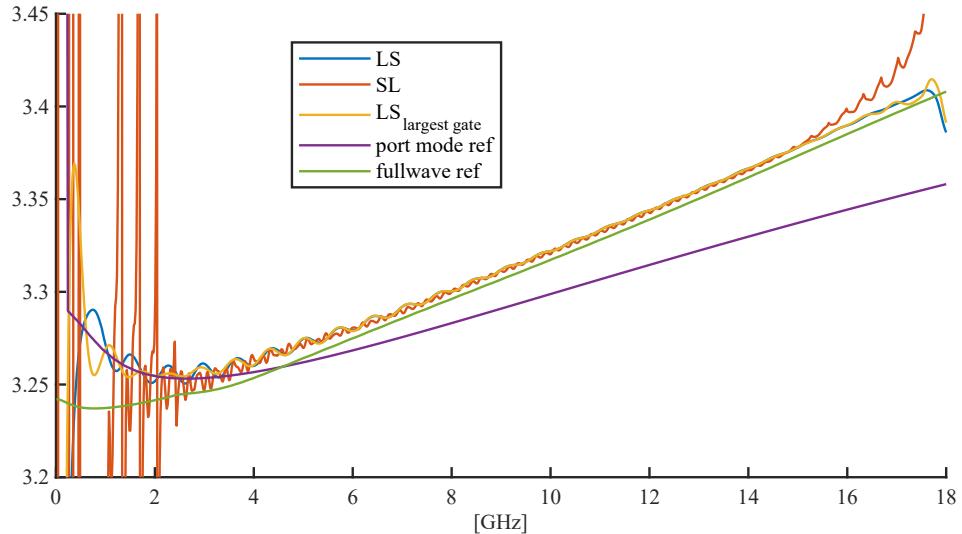


Figure 3: Simulated data retrieved effective permittivity compared with  $\varepsilon_{eff}$  calculated from the  $S_{21}$  of a full-wave simulation of a microstrip section (terminated on adaptive waveguide ports), and effective dielectric constant computed by the port mode solver of CST.

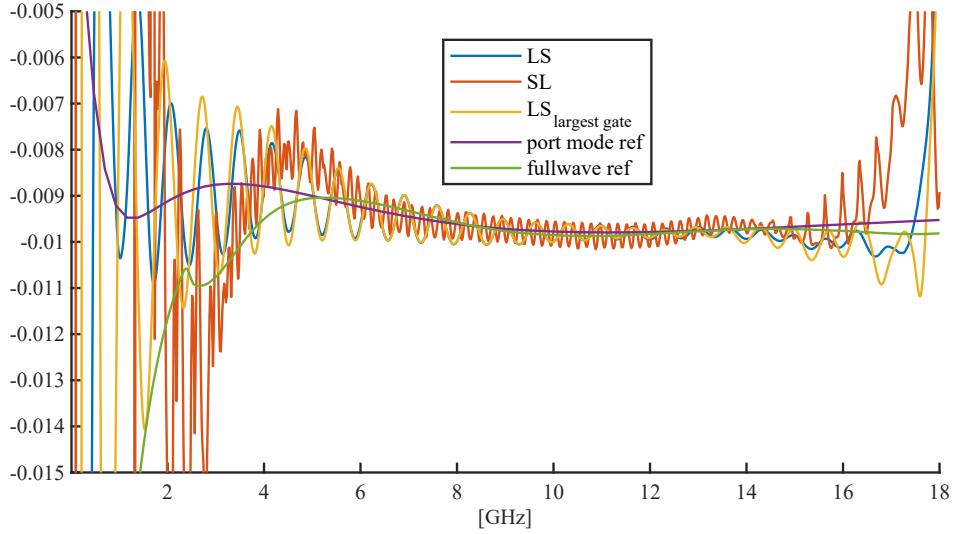


Figure 4: Simulated data retrieved effective loss tangent compared with  $\tan \delta_{eff}$  calculated from the  $S_{21}$  of a full-wave simulation of a microstrip section (terminated on adaptive waveguide ports), and effective loss tangent computed by the port mode solver of CST.

## 4.2 Measurements

## 5 Non-identical fixtures de-embedding error

### 5.1 Measurement results

In the ideal case,

## 6 Numerical model matching

## 7 Conclusions

The manufacturing process needs to be improved for repeatability. The material is lossy, might still be usable for a reflectarray, definitely not a good choice for traveling-wave antennas.

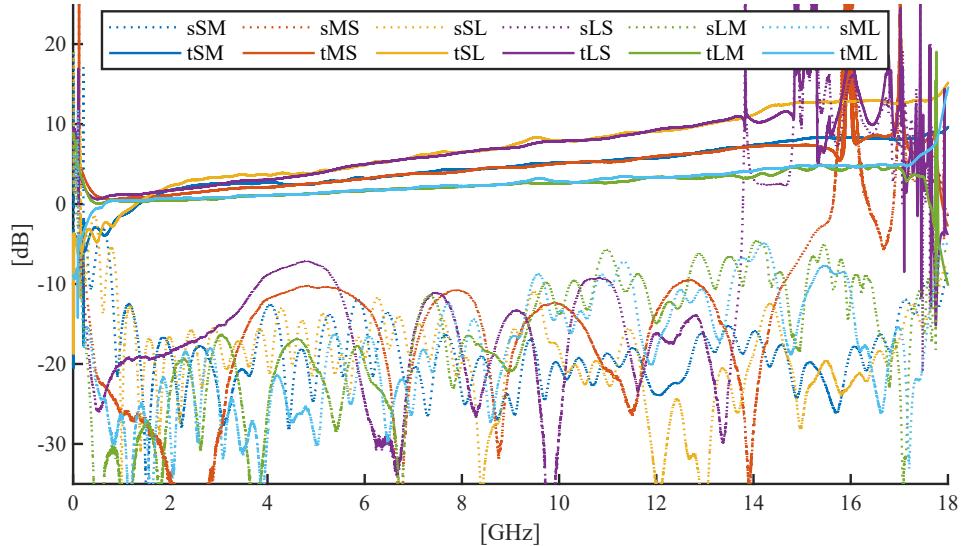


Figure 5: De-embedding results from the measurements of the test fixtures. Solid lines: transmissivity (s), dotted lines: reflectivity (t); for all the reference fixture – under test fixture combinations e.g. LS = long line as reference and short line de-embedding target. The transmissivity sign is chosen to always correspond to a negative-length section of lossy transmission line (for ease of comparison).

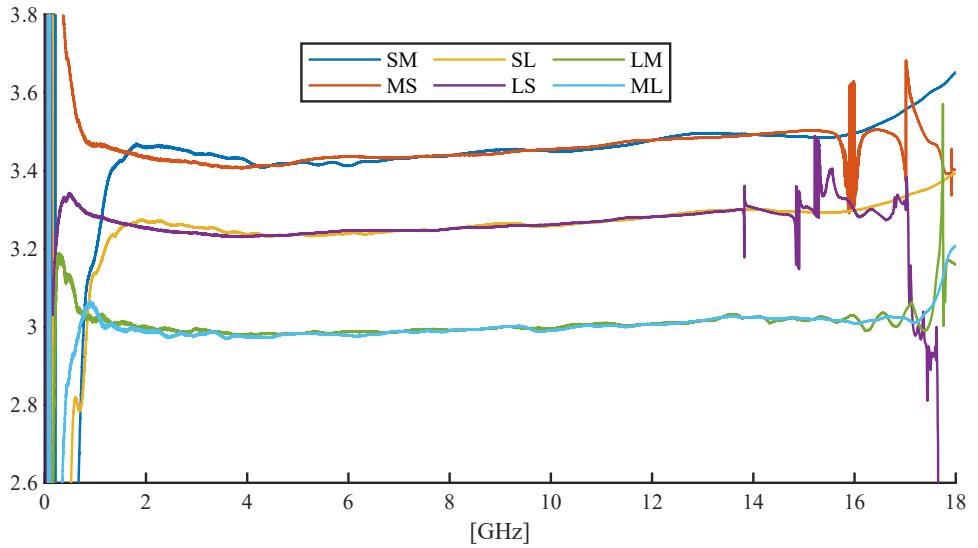


Figure 6: Measured data retrieved effective permittivity for all the reference fixture – under test fixture combinations.

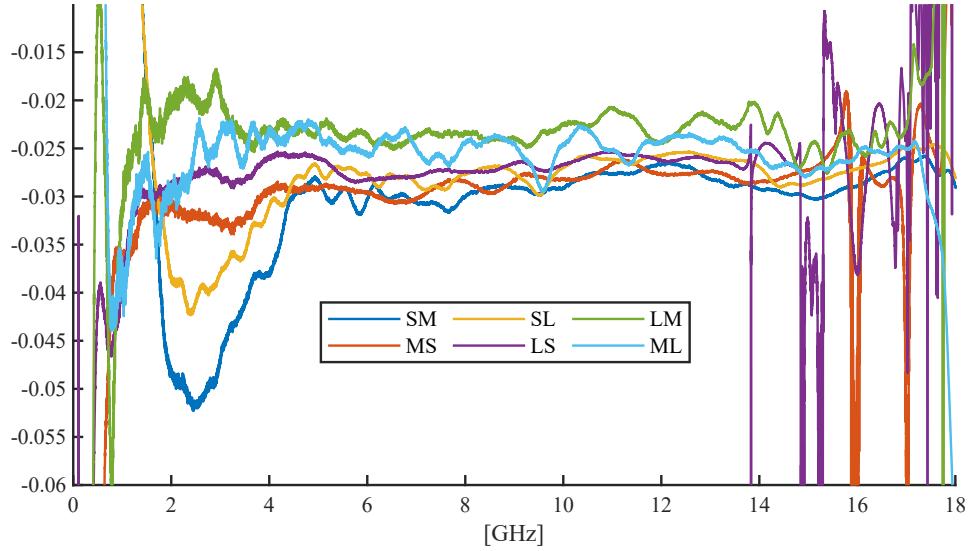


Figure 7: Measured data retrieved effective loss tangent for all the reference-fixture – under-test-fixture combinations.

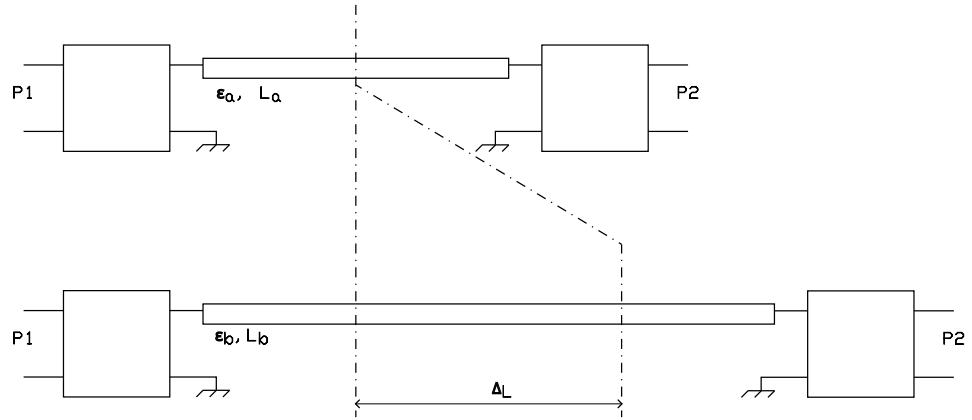


Figure 8: Two-fixtures schematic for the de-embedding procedure. The transitions are identical and the lines are of different lengths to produce a  $\Delta_L$ -long virtual line response. The error arises from the difference in phase velocity between the two lines (related to the effective permittivities  $\epsilon$ ).

## References

- [1] D. M. Pozar, *Microwave engineering; 3rd ed.* Hoboken, NJ: Wiley, 2005. [Online]. Available: <https://cds.cern.ch/record/882338>